

SPECIFICATION

Device Name : IGBT Module

Type Name : 7MBR35SB140-01

Spec. No. : MS6M 0556

Date : Jun. - 02 - 2000

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Matsumoto Factory

		DATE	NAME	APPROVED	Fuji Electric Co., Ltd.			
DRAWN		Jun. - 2 - '00	J. Kobayashi		DWG NO.	MS6M 0556	1 / 10	α
CHECKED		June - 2 - 00	S. Kato	J. Miyazaki				

Revised Records

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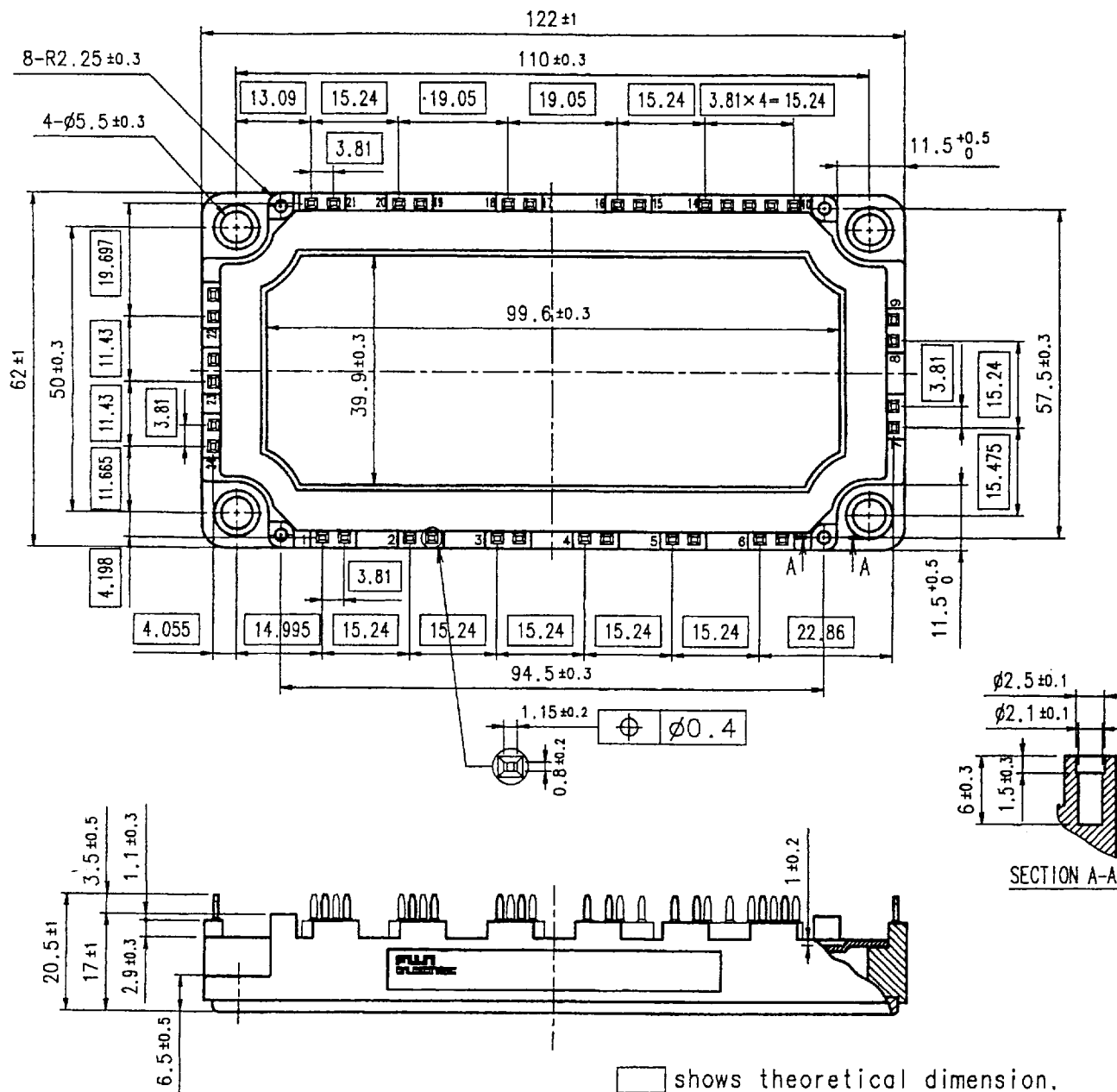
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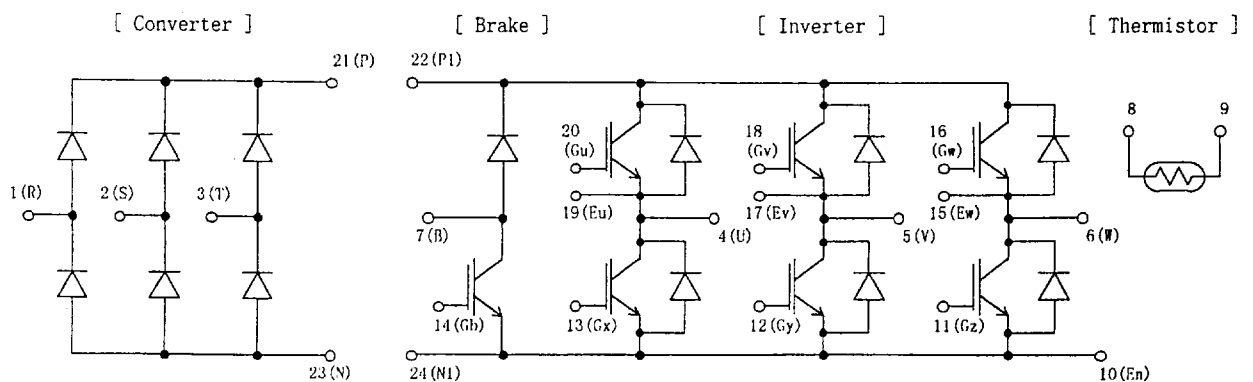
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1. Outline Drawing (Unit : mm)



2. Equivalent circuit



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3. Absolute Maximum Ratings (at Tc= 25C unless otherwise specified)

Items		Symbols	Conditions		Maximum Ratings	Units
Inverter	Collector-Emitter voltage	VCES			1400	V
	Gate-Emitter voltage	VGES			+20	V
	Collector current	Ic	Continuous	Tc=25C	50	A
				Tc=75C	35	
		Icp	1ms	Tc=25C	100	A
				Tc=75C	70	
		-Ic			35	A
Collector Power Dissipation	Pc	1 device		240	W	
Brake	Collector-Emitter voltage	VCES			1400	V
	Gate-Emitter voltage	VGES			+20	V
	Collector current	Ic	Continuous	Tc=25C	35	A
				Tc=75C	25	
		Icp	1ms	Tc=25C	70	A
				Tc=75C	50	
	Collector Power Dissipation	Pc	1 device		180	W
Repetitive peak reverse Voltage(Diode)	VRRM			1400	V	
Converter	Repetitive peak reverse Voltage	VRRM			1600	V
	Average Output Current	Io	50Hz/60Hz sine wave		35	A
	Surge Current (Non-Repetitive)	IFSM	Tj=150C,10ms		360	A
	I ² t (Non-Repetitive)	I ² t	half sine wave		648	A ² s
	Junction temperature	Tj			150	C
Storage temperature		Tstg			-40~ +125	C
Isolation voltage	between terminal and copper base ^{(*)1}	Viso	AC : 1min.		2500	V
	between thermistor and others ^{(*)2}				2500	V
Mounting Screw Torque ^{(*)3}					3.5	Nm

(*)1 All terminals should be connected together when isolation test will be done.

(*)2 Terminal 8 and 9 should be connected together. Terminal 1 to 7 and 10 to 24 should be connected together and shorted to copper base.

(*)3 Recommendable Value : 2.5~3.5 Nm (M5)

4. Electrical characteristics (at Tj= 25C unless otherwise specified)

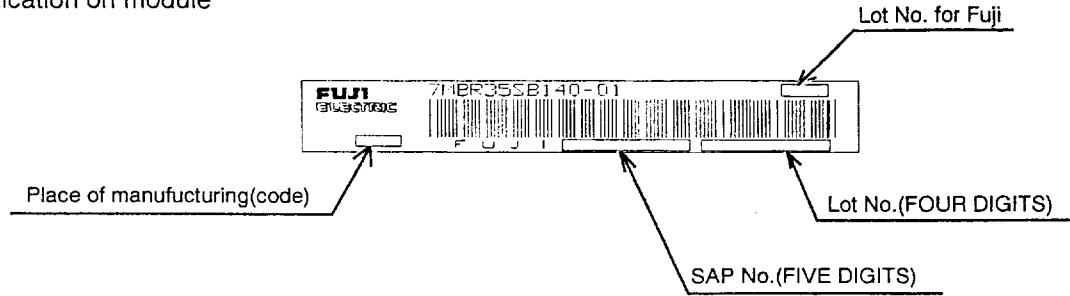
	Items	Symbols	Conditions	Characteristics			Units
				min.	typ.	Max.	
Inverter	Zero gate voltage Collector current	ICES	VGE = 0 V, VCE ^(*) 1400 V			1.0	mA
	Gate-Emitter leakage current	IGES	VCE = 0 V, VGE = +20 V			200	nA
	Gate-Emitter threshold voltage	VGE(th)	VCE = 20 V, Ic = 35 mA	5.5	7.2	8.5	V
	Collector-Emitter saturation voltage	VCE(sat)	VGE = 15 V, chip		2.2		V
			Ic = 35 A terminal		2.35	2.7	
	Input capacitance	Cies	VGE = 0 V, VCE = 10 V f = 1 MHz		4200		pF
	Turn-on time	ton	Vcc= 800 V		0.35	1.2	us
		tr	Ic = 35 A		0.25	0.6	
		tr(0)	VGE = +15 V		0.1		
	Turn-off time	toff	RG = 33 ohm		0.45	1.0	
		tf			0.08	0.3	
Brake	Forward on voltage	VF	IF = 35 A chip		2.4		V
			terminal		2.55	3.4	
	Reverse recovery time	trr	IF = 35 A			350	ns
	Zero gate voltage Collector current	ICES	VGE = 0 V, VCE ^(*) 1400 V			1.0	mA
	Gate-Emitter leakage current	IGES	VCE = 0 V, VGE = +20 V			200	nA
	Collector-Emitter saturation voltage	VCE(sat)	VGE = 15 V, chip		2.2		V
			Ic = 25 A terminal		2.35	2.8	
	Turn-on time	ton	Vcc= 800 V		0.35	1.2	us
		tr	Ic = 25 A		0.25	0.6	
	Turn-off time	toff	VGE = +15 V		0.45	1.0	
		tf	RG = 51 ohm		0.08	0.3	
Converter	Reverse current	IRRM	VR = 1400 V			1.0	mA
	Forward on voltage	VFM	IF = 35 A chip		1.1		V
			terminal		1.2	1.5	
Thermistor	Reverse current	IRRM	VR = 1600 V			1.0	mA
	Resistance	R	T = 25C		5000		ohm
			T = 100C	465	495	520	
	B value	B	T = 25/50C	3305	3375	3450	K

5. Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	Max.	
Thermal resistance (1 device)	Rth(j-c)	Inverter IGBT			0.52	C/W
		Inverter FWD			0.90	
		Brake IGBT			0.69	
		Converter Diode			0.75	
Contact Thermal resistance	Rth(c-f)	with Thermal Compound ^(*)		0.05		C/W

* This is the value which is defined mounting on the additional cooling fin with thermal compound.

6. Indication on module



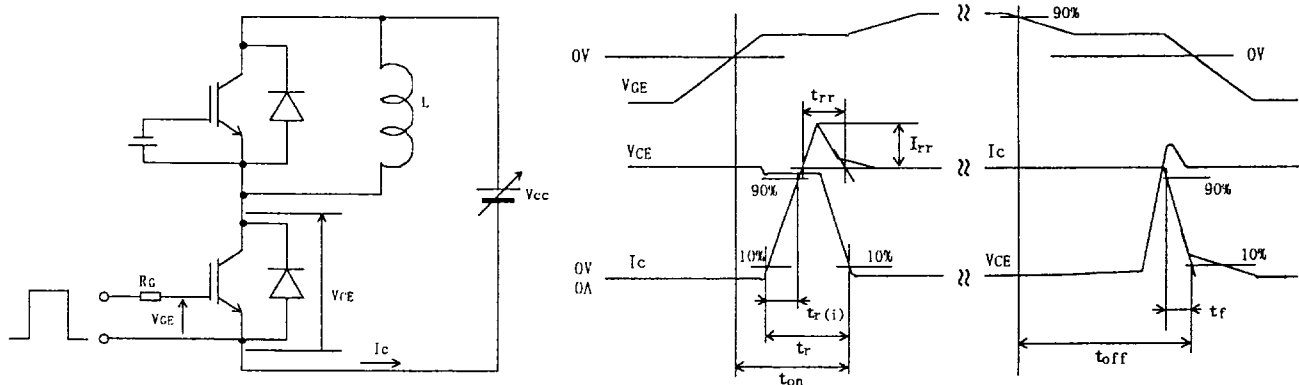
7. Applicable category

This specification is applied to Power Integrated Module named 7MBR35SB140-01 .

8. Storage and transportation notes

- The module should be stored at a standard temperature of 5 to 35°C and humidity of 45 to 75% .
- Store modules in a place with few temperature changes in order to avoid condensation on the module surface.
- Avoid exposure to corrosive gases and dust.
- Avoid excessive external force on the module.
- Store modules with unprocessed terminals.
- Do not drop or otherwise shock the modules when transporting.
- Please connect adequate fuse or protector of circuit between three-phase line and this product to prevent the equipment from causing secondary destruction.

9. Definitions of switching time



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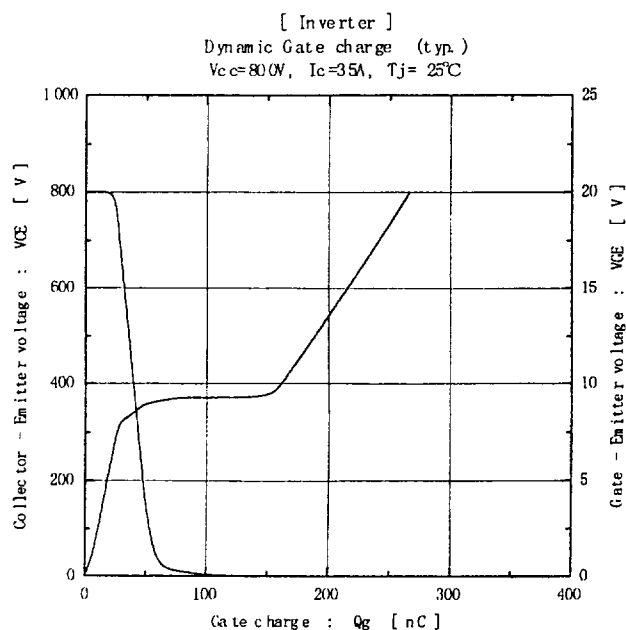
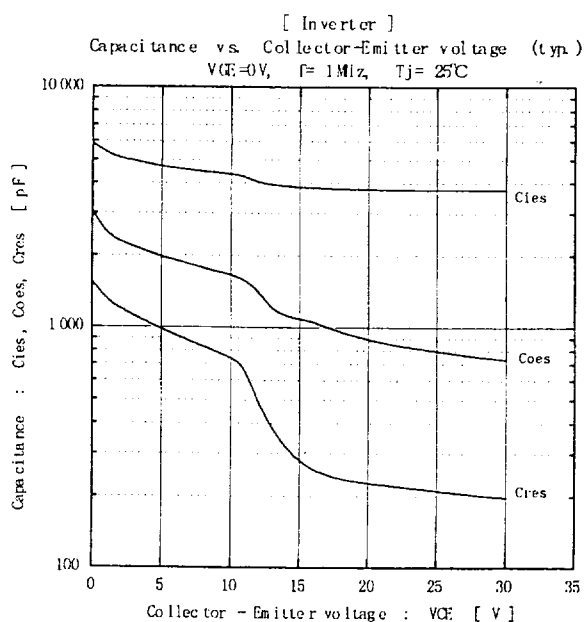
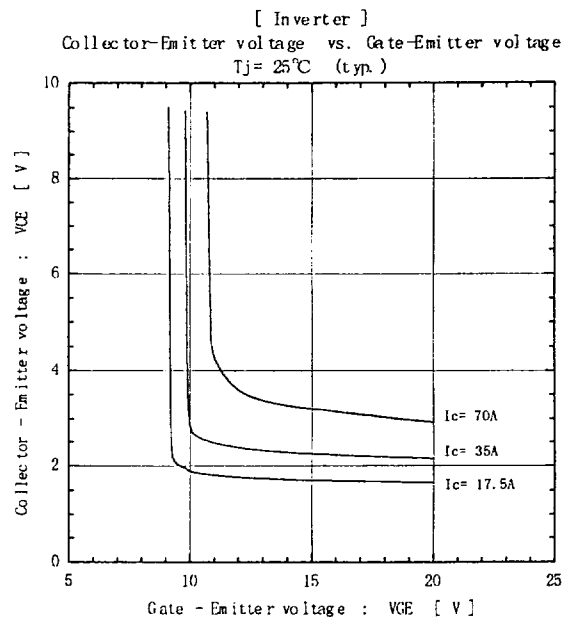
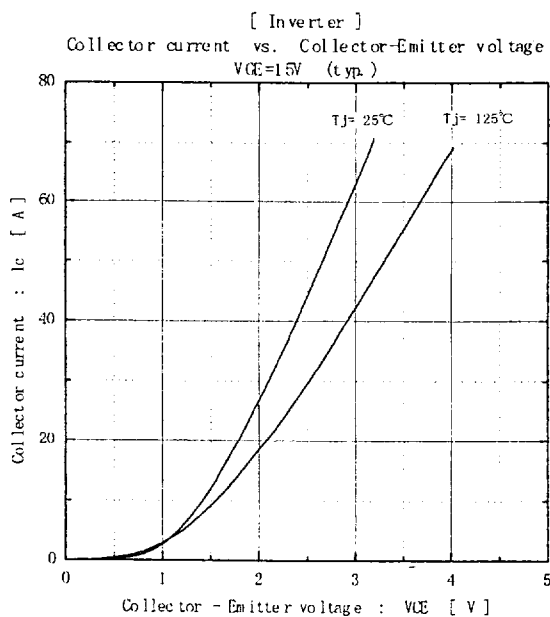
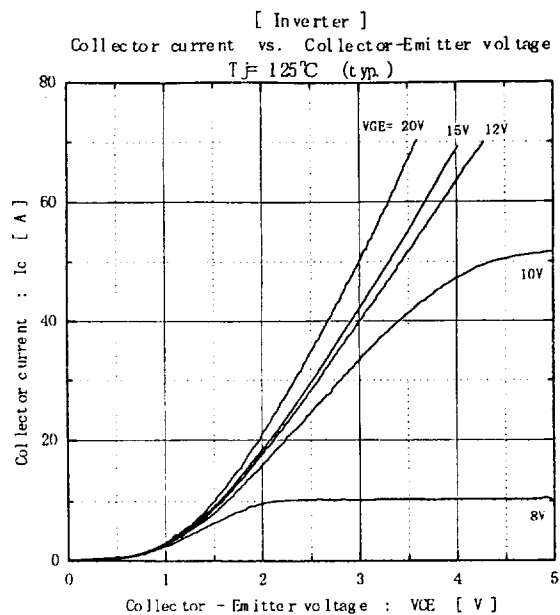
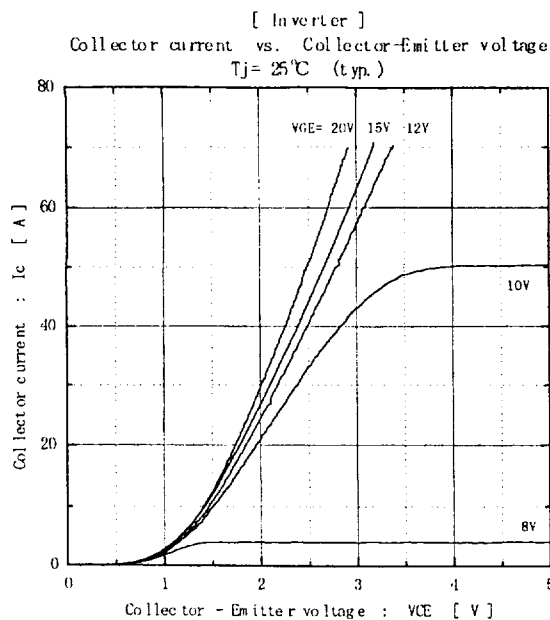
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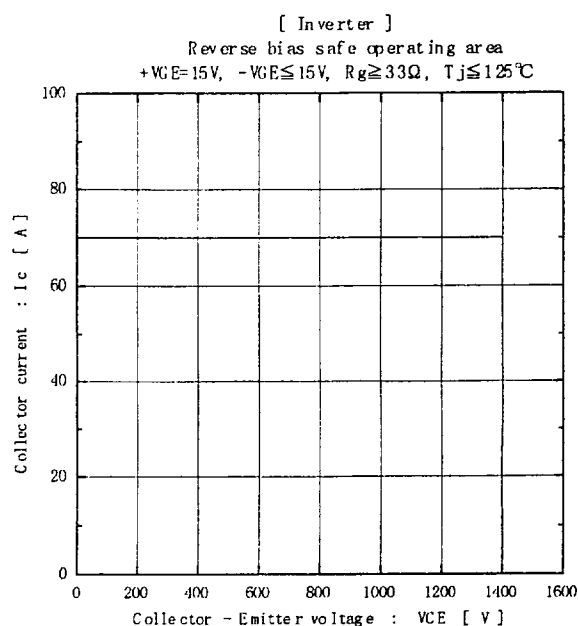
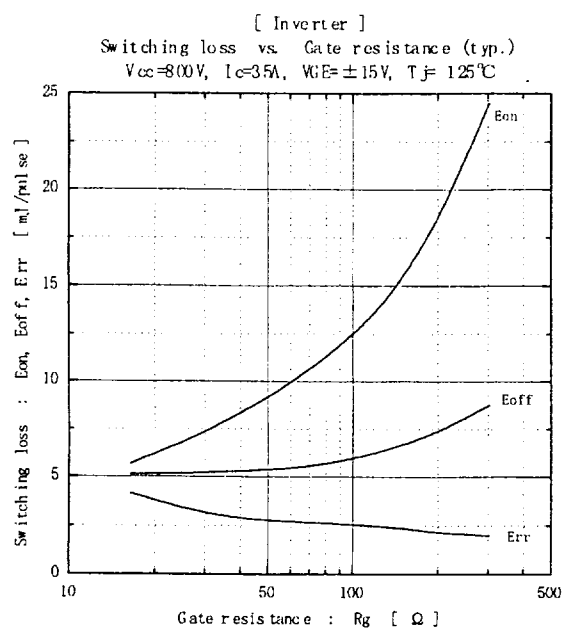
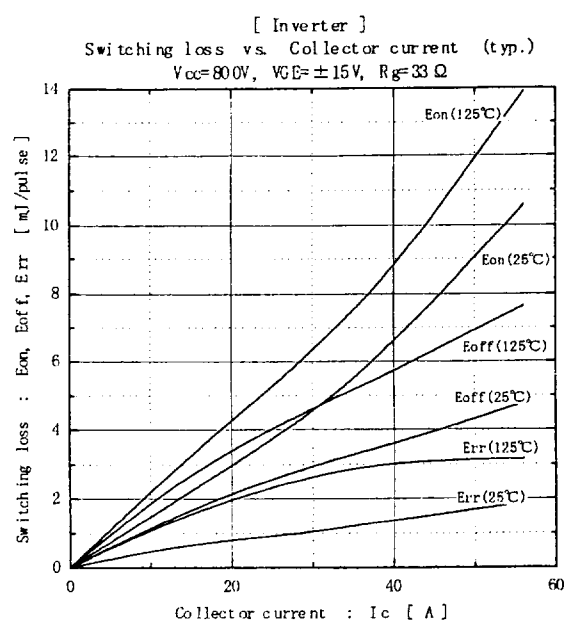
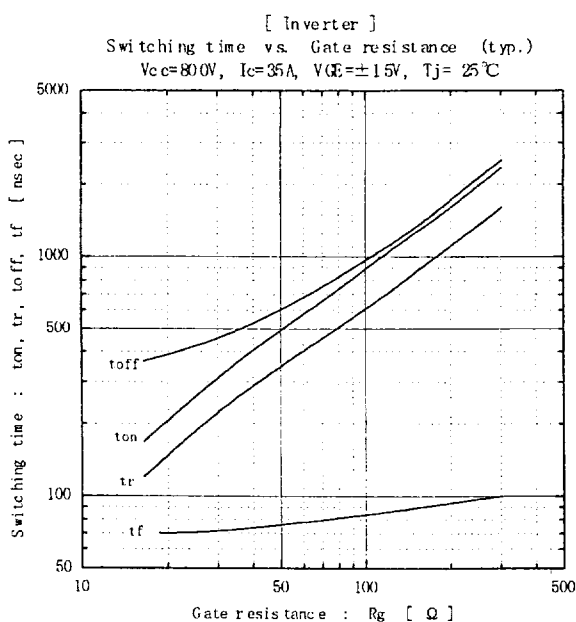
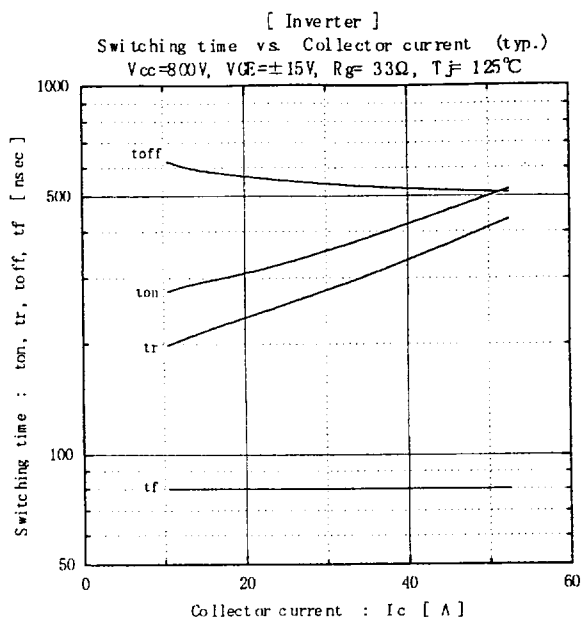
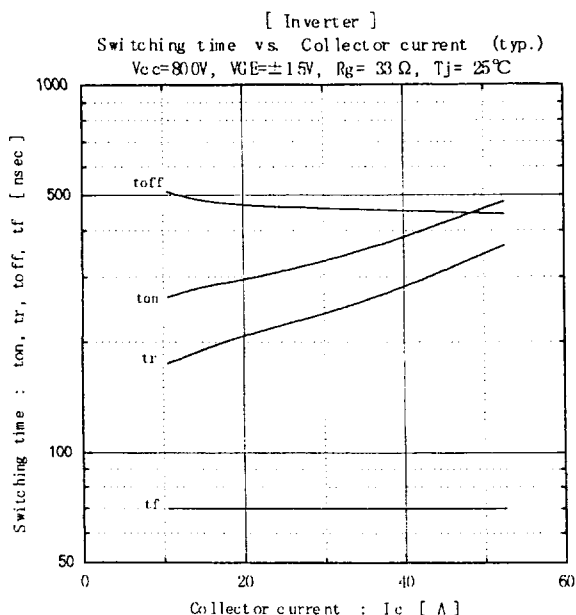
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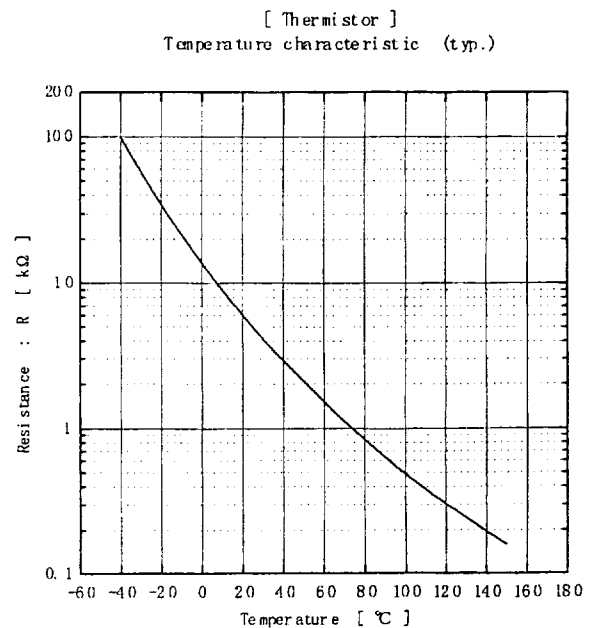
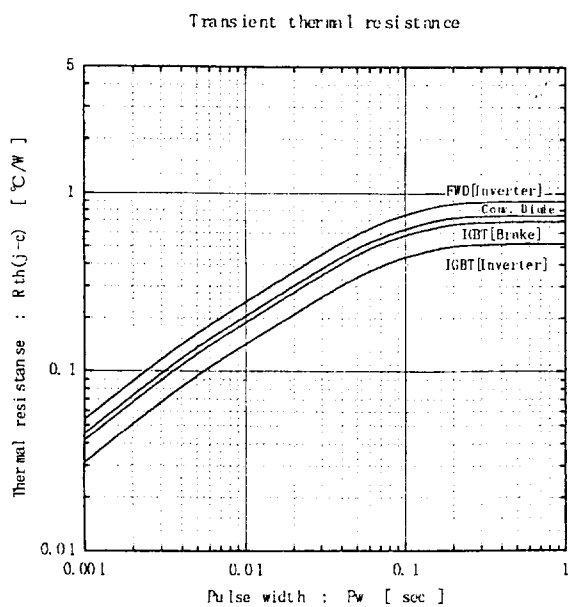
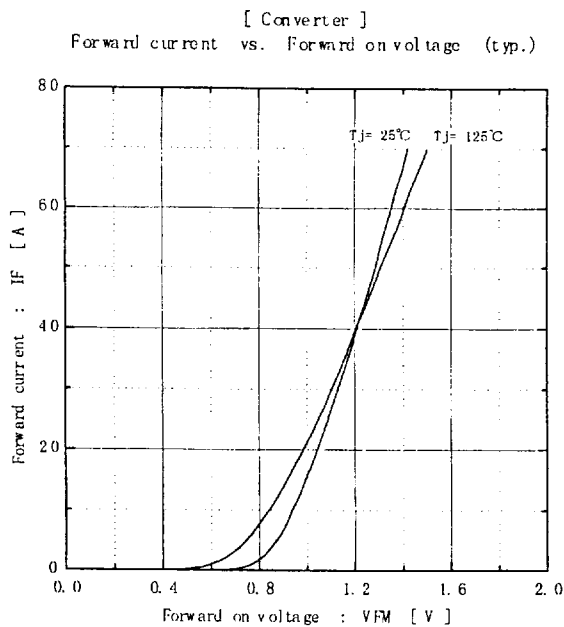
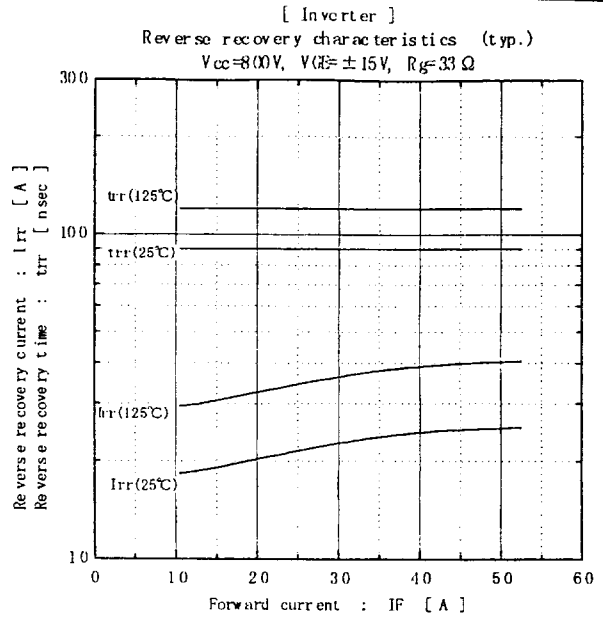
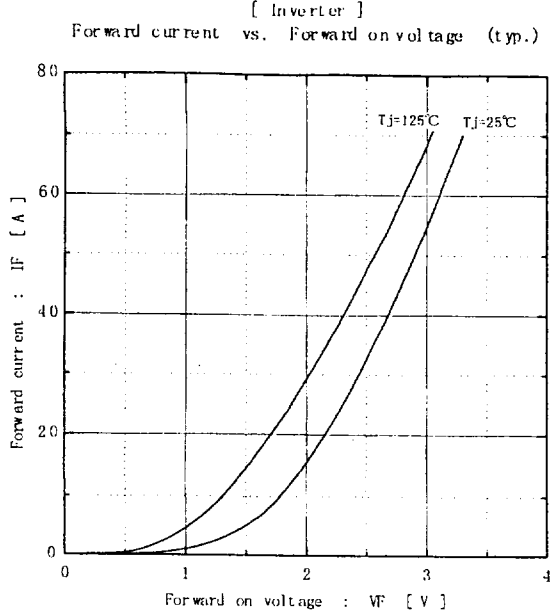
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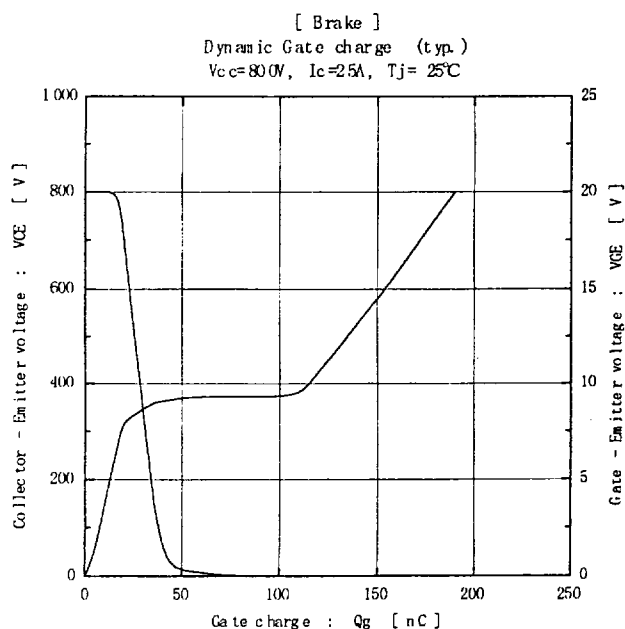
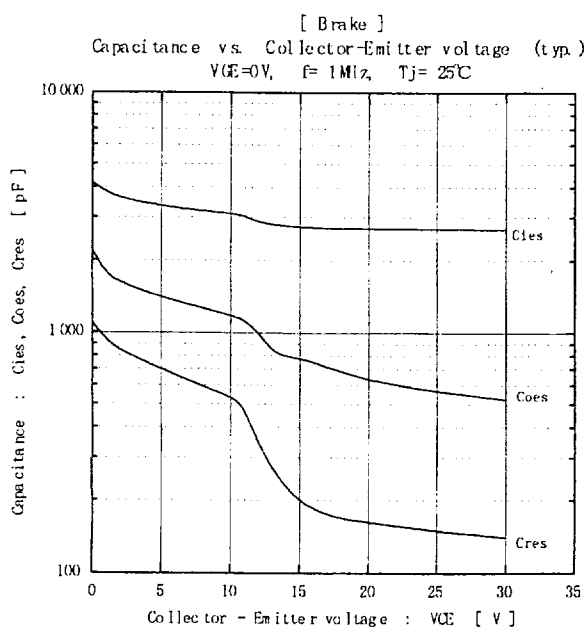
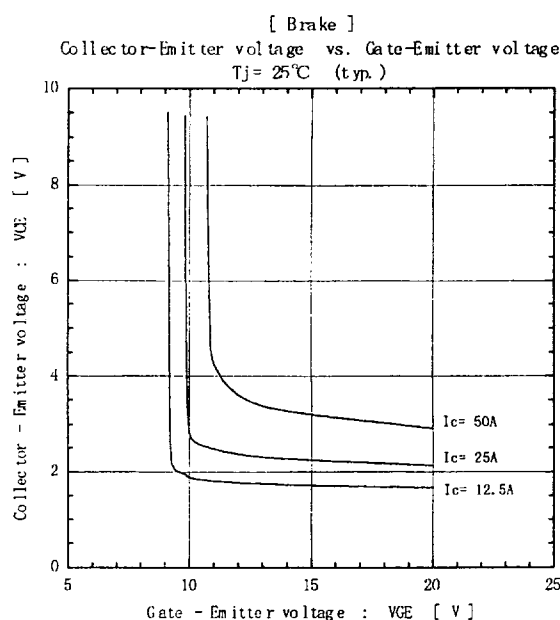
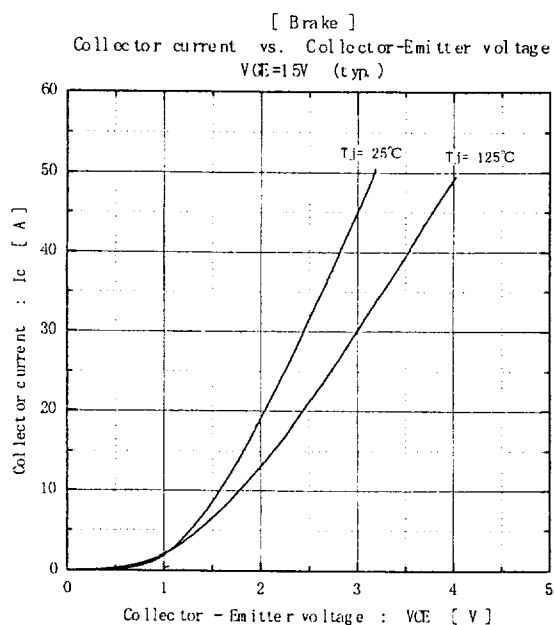
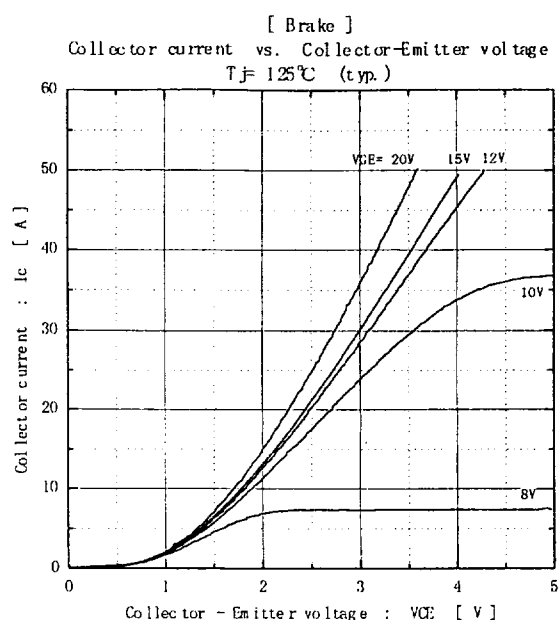
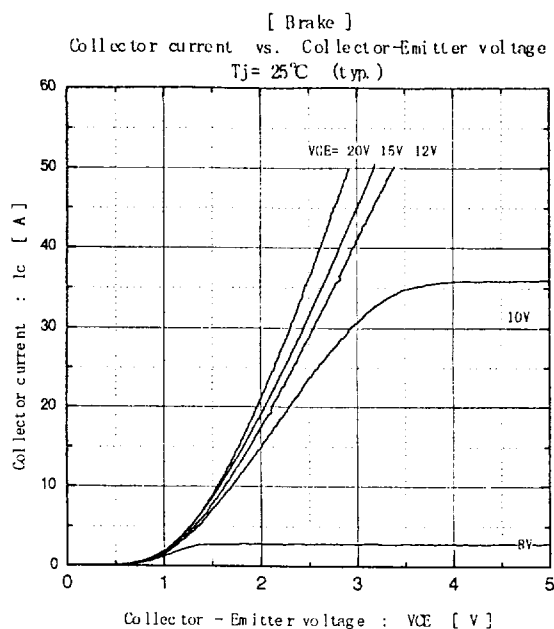
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